
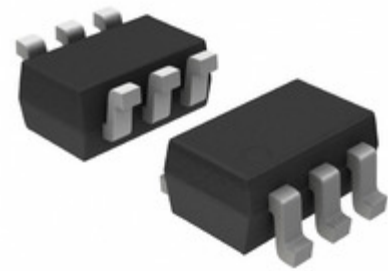











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|---|--------------------------------|--|
|  | NTJD3158CT2G | |
| | Hersteller-Teilenummer: | NTJD3158CT2G |
|  | Hersteller / Marke: | AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: | MOSFET N/P-CH 20V SC88-6 |
| <p>Image may be representation. See specs for product details.</p> | Datenblätter: |  NTJD3158CT2G.pdf |
| | RoHs Status: | Bleifrei / RoHS-konform |
| | Lagerzustand: | New original, 18578 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |

Spezifikationen

| | |
|--|--|
| Teilenummer | NTJD3158CT2G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N/P-CH 20V SC88-6 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 18578 pcs Stock |
| Serie | - |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Leistung - max | 270mW |
| Verpackung / Gehäuse | 6-TSSOP, SC-88, SOT-363 |
| Supplier Device-Gehäuse | SC-88/SC70-6/SOT-363 |
| Typ FET | N and P-Channel |
| FET-Merkmal | Logic Level Gate |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 630mA, 820mA |
| Rds On (Max) @ Id, Vgs | 375 mOhm @ 630mA, 4.5V |
| VGS (th) (Max) @ Id | 1.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 3nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 46pF @ 20V |
| Verpackung | Tape & Reel (TR) |

NTJD3158CT2G ist neu im Original. Suche NTJD3158CT2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTJD3158CT2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTJD3158CT2G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|---|---|
|  <p>NTJD2152PT4 AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p> |  <p>NTJD2152PT2G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p> |  <p>NTJD4001NT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 0.25A SOT-363</p> |  <p>NTJD4105CT1 ON ON SOT363</p> |
|  <p>NTJD4001NT2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 0.25A SOT363</p> |  <p>NTJD4001NT1 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 0.25A SOT363</p> |  <p>NTJD4105CT1G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V/8V SOT-363</p> |  <p>NTJD3115PT1G ON NTJD3115PT1G ON</p> |

heiße Teile

Mehr

| | | | | |
|----------------------|-------------------|--------------|--------------------|--------------------|
| 218-0844012 | AAT3215IGV-2.8-T1 | AT89LP2052 | BS62LV1027PCP-55 | BT136S-800F |
| C1608X8R1H472K080AA | FDC606P-NL | FZ800R33KF1 | GRM1887U2A6R4DZ01D | GRM188R61A106MAALD |
| IRF630STRLPBF | MG50Q6ES50 | NTJD1155LT1G | NTJD2152PT1 | NTJD2152PT1G |
| NTJD3115PT1G | NTJD3158CT1G | NTJD4001NT1G | NTJD4001NT2G | NTJD4105CT1G |
| NTJD4105CT2G | NTJD4152PT1 | NTJD4152PT1G | NTJD4158CT1G | NTJD4158CT2G |
| NTJD4401NT1 | NTJD4401NT1G | NTJD4401NT2 | NTJD5121NT1G | NTJD5121NT2G |
| NTJS3151PT1G | NTJS3157NT1G | NTJS4151PT1G | NTJS4160NT1G | NTJS4405NT1G |
| NTJS4405NT4G | NTJS4405UT1 | PF06V4B15 | PTFB212503FL | RB520ZS-30 |
| RM60D2Z-H | SD5000C30RPBF | SKD100/14 | SKIIP38NAB126V1 | SKM50GB12T4 |
| SST39VF040-70-4C-WHE | UBA2033TS | UCC37321DRG4 | ULQ2804LWTR | XN0438100L |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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